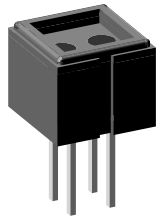
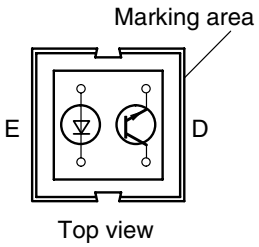
Reflective Optical Sensor with Transistor Output

Description

The CNY70 is a reflective sensor that includes an infrared emitter and phototransistor in a leaded package which blocks visible light.





Features

- Package type: Leaded
- Detector type: Phototransistor
- Dimensions: L 7 mm x W 7 mm x H 6 mm
- Peak operating distance: < 0.5 mm
- Operating range: 0 mm to 4.5 mm
- Typical output current under test: I_C = 1 mA
- Daylight blocking filter
- Emitter wavelength 950 nm
- Lead (Pb)-free soldering released
- Lead (Pb)-free component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Minimum order quantity 4000 pcs in tubes, 80 pcs/tube

Applications

Optoelectronic scanning and switching devices i.e., index sensing, coded disk scanning etc. (optoelectronic encoder assemblies).

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Coupler

Parameter	Test condition	Symbol	Value	Unit
Total power dissipation	$T_{amb} \leq 25$ °C	P_{tot}	200	mW
Ambient temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	Distance to case 2 mm, t ≤ 5 s	T_{sd}	260	°C

Input (Emitter)

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	5	V
Forward current		I_F	50	mA
Forward surge current	$t_p \leq 10$ µs	I_{FSM}	3	A
Power dissipation	$T_{amb} \leq 25$°C	P_V	100	mW
Junction temperature		T_j	100	°C

Output (Detector)

Parameter	Test condition	Symbol	Value	Unit
Collector emitter voltage		V_{CEO}	32	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Power dissipation	$T_{amb} \leq 25$ °C	P_V	100	mW
Junction temperature		T_j	100	°C

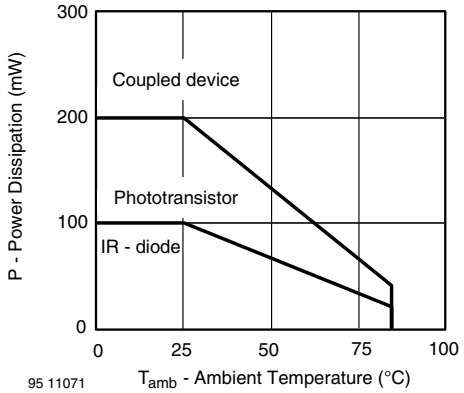


Figure 1. Power Dissipation Limit vs. Ambient Temperature

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Coupler

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector current	V_{CE} = 5 V, I_F = 20 mA, d = 0.3 mm (figure 2)	I_C [1)]	0.3	1.0		mA
Cross talk current	V_{CE} = 5 V, I_F = 20 mA (figure 1)	I_{CX} [2)]			600	nA
Collector emitter saturation voltage	I_F = 20 mA, I_C = 0.1 mA, d = 0.3 mm (figure 2)	V_{CEsat} [1)]			0.3	V

1) Measured with the 'Kodak neutral test card", white side with 90 % diffuse reflectance

2) Measured without reflecting medium

Input (Emitter)

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	I_F = 50 mA	V_F		1.25	1.6	V
Radiant intensity	I_F = 50 mA, t_P = 20 ms	I_e			7.5	mW/sr
Peak wavelength	I_F = 100 mA	λ_P	940			nm
Virtual source diameter	Method: 63 % encircled energy	Ø		1.2		mm

Output (Detector)

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector emitter voltage	I_C = 1 mA	V_{CEO}	32			V
Emitter collector voltage	I_E = 100 µA	V_{ECO}	5			V
Collector dark current	V_{CE} = 20 V, I_f = 0, E = 0	I_{CEO}			200	nA

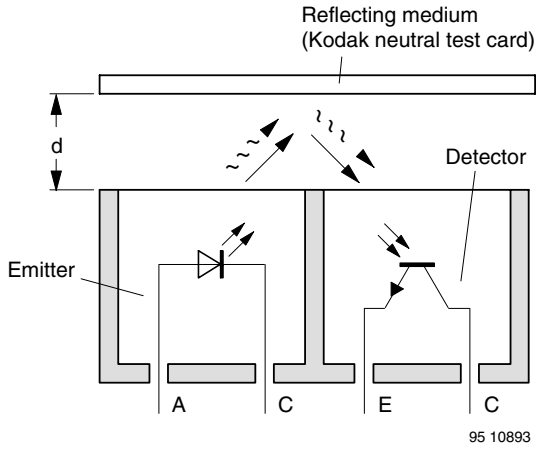


Figure 2. Test Condition

Typical Characteristics

T_{amb} = 25 °C unless otherwise specified

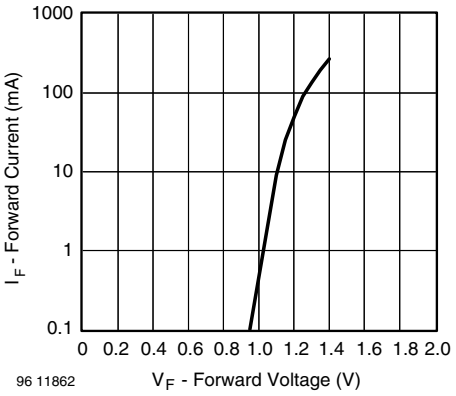


Figure 3. Forward Current vs. Forward Voltage

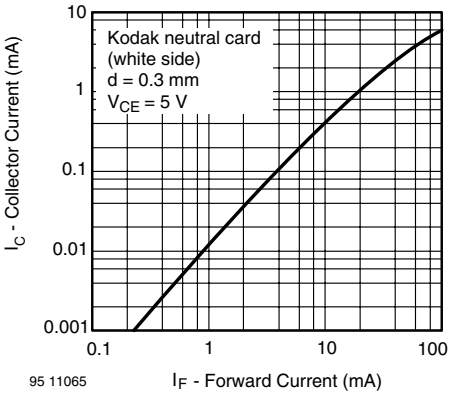


Figure 5. Collector Current vs. Forward Current

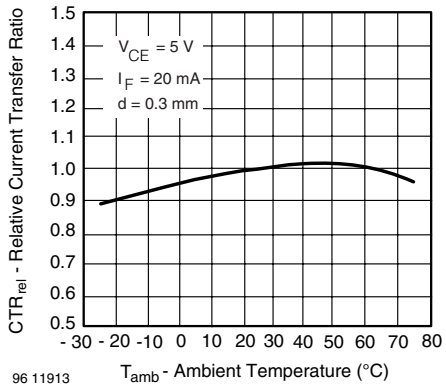


Figure 4. Relative Current Transfer Ratio vs. Ambient Temperature

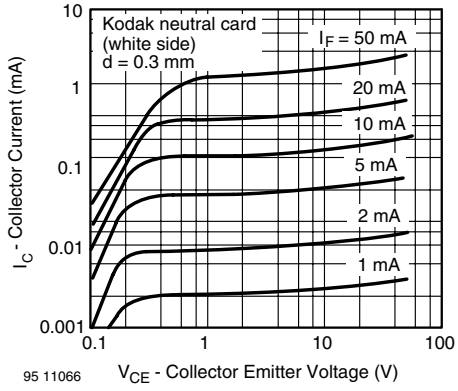


Figure 6. Collector Current vs. Collector Emitter Voltage

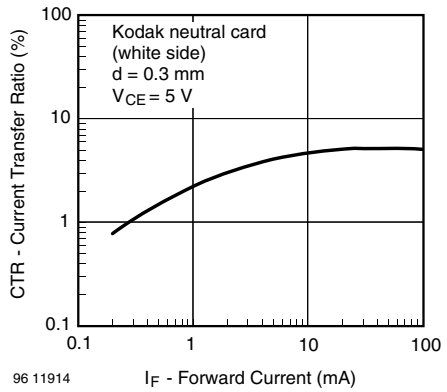


Figure 7. Current Transfer Ratio vs. Forward Current

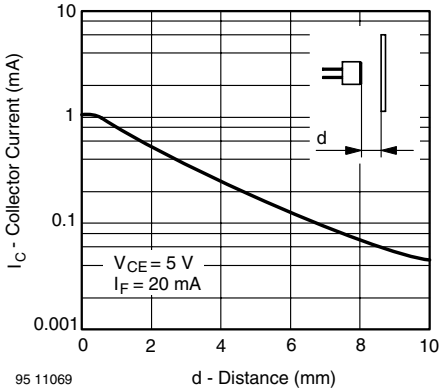


Figure 9. Collector Current vs. Distance

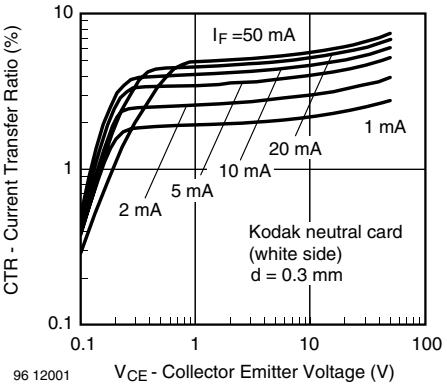


Figure 8. Current Transfer Ratio vs. Collector Emitter Voltage

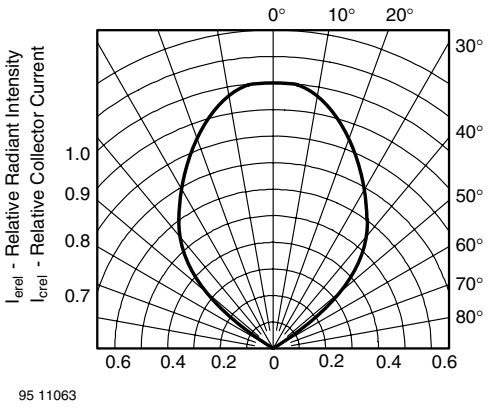


Figure 10. Relative Radiant Intensity/Collector Current vs. Angular Displacement

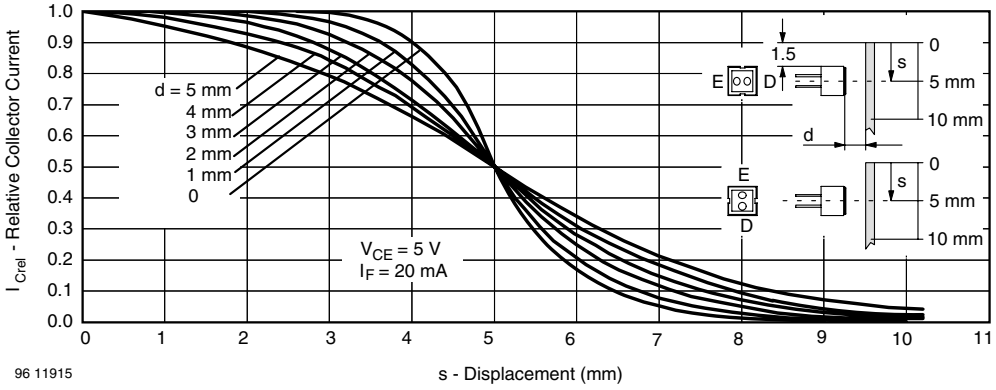
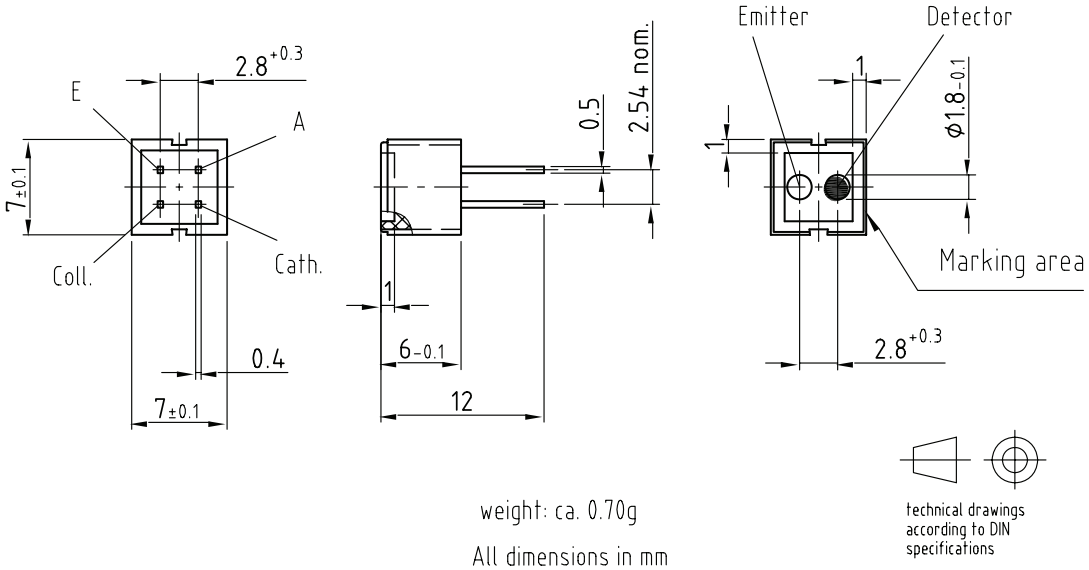


Figure 11. Relative Collector Current vs. Displacement

Package Dimensions



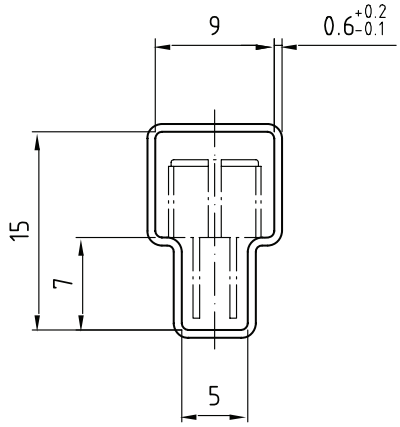
weight: ca. 0.70g

All dimensions in mm

Drawing-No.: 6.544-5062.01-4
Issue: 6; 03.05.06
95 11345

Drawing refers to following types: CNY 70

Tube Dimensions



With rubber stopper
Tolerance: ±0.5mm
Length: 575±1mm

All dimensions in mm

Drawing-No.: 9.700-5097.01-4
Issue: 1; 25.02.00
20291

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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